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# LV8406T

# Bi-CMOS IC 2ch Forward/Reverse Motor Driver



http://onsemi.com

#### **Overview**

LV8406T is a 2-channel forward/reverse motor driver IC using D-MOS FET for output stage. As MOS circuit is used, it supports the PWM input. Its features are that the on resistance  $(0.75\Omega \text{ typ})$  and current dissipation are low. It also provides protection functions such as heat protection circuit and reduced voltage detection and is optimal for the motors that need high-current.

#### **Functions**

- 2-channel forward/reverse motor driver.
- Low power consumption.
- Low-ON resistance  $0.75\Omega$ .

- Built-in low voltage reset and thermal shutdown circuit.
- Four mode function forward/reverse, brake, stop.
- Built-in charge pump.

### **Specifications**

**Absolute Maximum Ratings** at Ta = 25°C, SGND = PGND = 0V

Parameter	Symbol	Conditions	Ratings	Unit
Power supply voltage (for load)	VM max	VM1, VM2	-0.5 to 16.0	V
Power supply voltage (for control)	V <sub>CC</sub> max		-0.5 to 6.0	V
Output current	I <sub>O</sub> max		1.4	Α
Output peak current	I <sub>O</sub> peak	t ≤ 10ms	2.5	Α
Input voltage	V <sub>IN</sub> max		-0.5 to V <sub>CC</sub> +0.5	٧
Allowable power dissipation	Pd max	Mounted on a specified board*	3.1	W
Operating temperature	Topr		-30 to +85	°C
Storage temperature	Tstg		-55 to +150	°C

 $<sup>^{\</sup>star}$  Specified board : 90mm  $\times$  90mm  $\times$  1.6mm, glass epoxy 2-layer board (2S0P).

Caution 1) Absolute maximum ratings represent the value which cannot be exceeded for any length of time.

Caution 2) Even when the device is used within the range of absolute maximum ratings, as a result of continuous usage under high temperature, high current, high voltage, or drastic temperature change, the reliability of the IC may be degraded. Please contact us for the further details.

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### LV8406T

#### Allowable Operating Conditions at Ta = 25°C, SGND = PGND = 0V

Parameter	Symbol	Conditions	Ratings	Unit
Power supply voltage (VM pin)	VM		1.5 to 15.0	V
Power supply voltage (V <sub>CC</sub> pin)	V <sub>CC</sub>		2.8 to 5.5	V
Input signal voltage	V <sub>IN</sub>		0 to V <sub>CC</sub>	V
Input signal frequency	f max		200	kHz

# $\textbf{Electrical Characteristics} \ Ta = 25^{\circ}C, \ V_{CC} = 3.0V, \ VM = VS = 6.0V, \ SGND = PGND = 0V, \ unless \ otherwise \ specified.$

Parameter		Symbol	Conditions	Remarks	Ratings			1.1-24
				Hemarks	min	typ	max	Unit
Standby load current drain		IMO	EN = 0V	1			1.0	μΑ
Standby control current drain		ICO	EN = IN1 = IN2 = IN3 = IN4 = 0V	2			1.0	μΑ
Standby load current drain2		IMO2	V <sub>CC</sub> = 0V, VM = VS = 6V				1.0	μΑ
Operating contr	ol current drain	IC1	EN = 3V, with no load	3		0.85	1.2	mA
High-level input voltage		V <sub>IH</sub>	2.7 ≤ V <sub>CC</sub> ≤ 5.5V		0.6×V <sub>CC</sub>		V <sub>CC</sub>	V
Low-level input	voltage	V <sub>IL</sub>	2.7 ≤ V <sub>CC</sub> ≤ 5.5V		0		0.2×V <sub>CC</sub>	V
High-level input current (EN1, EN2, IN1, IN2, IN3, IN4)		I <sub>IH</sub> 1	V <sub>IN</sub> = 3V	4		15	25	μА
Low-level input current (EN1, EN2, IN1, IN2, IN3, IN4)		I <sub>IL</sub> 1	V <sub>IN</sub> = 0V	4	-1.0			μА
Pull-down resistance value		RDN	EN1, EN2, IN1, IN2, IN3, IN4		100	200	400	kΩ
Charge pump voltage		VG	V <sub>CC</sub> + VS		8.5	9.0	9.5	V
Output ON resistance 1		RON1	Sum of top and bottom sides ON resistance.	5		0.75	1.2	Ω
Output ON resistance 2		RON2	Sum of top and bottom sides ON resistance. V <sub>CC</sub> = 2.8V	5		1.0	1.5	Ω
Low-voltage detection voltage V		VCS	V <sub>CC</sub> pin voltage is monitored	6	2.15	2.30	2.45	٧
Thermal shutdown temperature		Tth	Design guarantee value *	7	150	180	210	°C
Output block	Turn-on time	TPLH		8		0.2	0.4	μS
	Turn-off time	TPHL		8		0.2	0.4	μS

<sup>\*:</sup> Design guarantee value and no measurement is preformed.

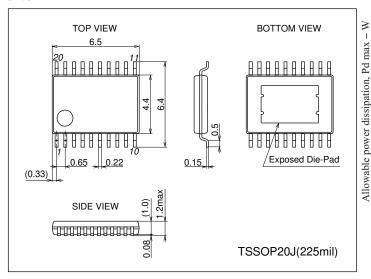
#### Remarks

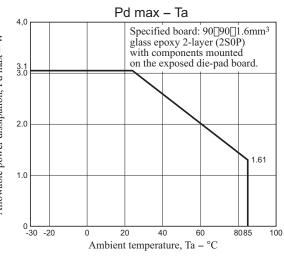
- 1. Current consumption when output at the VM pin is off.
- 2. Current consumption when the  $V_{\hbox{\footnotesize{CC}}}$  pin when in standby mode.
- 3. Current consumption at the V<sub>CC</sub> pin when EN is 3V (standby mode).
- 4. Pins EN1, 2, IN1, 2, 3, and 4 are all pulled down.
- 5. Sum of upper and lower saturation voltages of OUT pin divided by the current.
- 6. All power transistors are turned off if a low  $V_{\hbox{\scriptsize CC}}$  condition is detected.
- 7. All output transistors are turned off if the thermal protection circuit is activated. They are turned on again as the temperature goes down.
- 8. Rising time from 10 to 90% and falling time from 90 to 10% are specified.

### **Package Dimensions**

unit: mm (typ)

3279



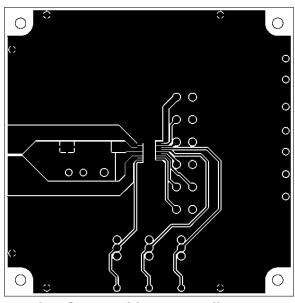


#### **Substrate Specifications**

Size :  $90\text{mm} \times 90\text{mm} \times 1.6\text{mm}$  (2-layer substrate [2S0P])

Material : Glass epoxy

Copper wiring density : L1 = 95% / L2 = 95%



L1: Copper wiring pattern diagram

L2: Copper wiring pattern diagram

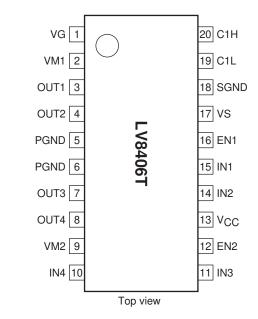
#### **Cautions**

- 1) The data for the case with the Exposed Die-Pad substrate mounted shows the values when 90% or more of the Exposed Die-Pad is wet.
- 2) For the set design, employ the derating design with sufficient margin.

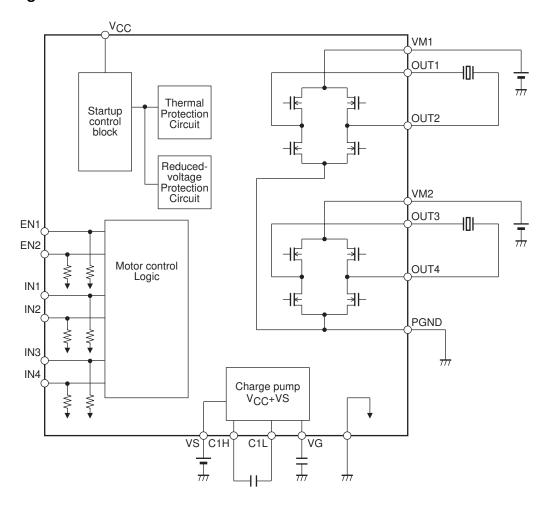
Stresses to be derated include the voltage, current, junction temperature, power loss, and mechanical stresses such as vibration, impact, and tension. Accordingly, the design must ensure these stresses to be as low or small as possible. The guideline for ordinary derating is shown below:

- (1)Maximum value 80% or less for the voltage rating
- (2)Maximum value 80% or less for the current rating
- (3)Maximum value 80% or less for the temperature rating
- 3) After the set design, be sure to verify the design with the actual product. Confirm the solder joint state and verify also the reliability of solder joint for the Exposed Die-Pad, etc. Any void or deterioration, if observed in the solder joint of these parts, causes deteriorated thermal conduction, possibly resulting in thermal destruction of IC.

# **Pin Assignment**



# **Block Diagram**



- \* Connect a kickback absorption capacitor as near as possible to the IC. Coil kickback may cause increase in VM line voltage, and a voltage exceeding the maximum rating may be applied momentarily to the IC, which results in deterioration or damage of the IC
- \* The pin VS is a terminal that supplies a source power supply of the charge pump circuit. The charge pump voltage,  $VG = VS + V_{CC}$  is generated. Apply the high voltage of VM1 or VM2.

# **Truth Table**

EN1 (EN2)	IN1 (IN3)	IN2 (IN4)	OUT1 (OUT3)	OUT2 (OUT4)	Charge pump	Mode
	Н	Н	L	L		Brake
	Н	L	Н	L	ON	Forward
Н	L	Н	L	Н	ON	Reverse
	L	L	Z	Z		Standby
L	-	-	Z	Z	OFF	All function stop

<sup>-:</sup> denotes a don't care value. Z: High-impedance

- In standby mode, consumption current serves as zero..
- \* All power transistors turn off and the motor stops driving when the IC is detected in low voltage or thermal protection mode.

# **Pin Functions**

	Dinnama	Description	Equivalent direvit
Pin No.	Pin name	Description	Equivalent circuit
20	C1H	Step-up capacitor connection pin.	VS VS VG
1 17	VG VS	Charge pump source voltage supply pin.	С1H О
19	C1L	Step-up capacitor connection pin.	Internal OSC C1L
16	EN1	Logic enable pin.	
12	EN2	(Pull-down resistor incorporated)	vcc
15	IN1	Driver output switching.	
14	IN2		\\\\
11	IN3		<b>★</b>
10	IN4		\$≥200kΩ 777 777
3	OUT1	Driver output.	○VM
4	OUT2		T VIVI
7 8	OUT3 OUT4		OUT OUT OUT PGND
2 9	VM1 VM2	Motor block power supply.	
13	V <sub>CC</sub>	Logic block power supply.	
18	SGND	Control block ground.	
5	PGND	Driver block ground.	
6	PGND		

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